



### **SDRI125 Series, Shielded SMD Power Inductors**





### ◆特征:

- 高饱和电流,低直流电阻
- 闭合磁路设计减少漏磁
- 自动贴装的高精度尺寸
- 多种封装尺寸和宽电感范围
- 符合 RoHS,无卤和 REACH

### ◆用途:

- 录影机
- 液晶电视
- 笔记本电脑
- 小型通信机器.
- DC/DC 转换器等

### ◆环境:

工作温度: -40℃ 至+125℃
 (包括线圈自身温升)

### ◆试验设备:

- 电感值:HP4284A, HP4285A 或同等仪器
- 电流:HP4284+42841A 或同等仪器
- 品质因子: HP4285A 或同等仪器
- 直流电阻: Chroma 16502 或同等仪器

#### Features:

- High saturation current, low DCR
- Close magnetic circuit design reduce leakage
- Hig hlyaccurate dimensions for automatic mounting
- Various package size and wide inductance range
- RoHS, Halogen Free and REACH Compliance

### Applications:

- Power supply for VTRs
- LCD televisions
- Notebook PCs
- Portable communication equipment
- DC/DC converters, etc

#### **Environmental Data:**

Operating Temperature: -40° to +125° (Including coils self-temperature rise)

### **Test Equipment:**

- L:HP4284A or HP4285A LCR meter or equivalent
- Isat & Irms: HP4284+42841A or equivalent
- Q: HP4285A or equivalent

**Product Identification:** 

• DCR:Chroma 16502 or equivalent

### ◆产品型号:

1	

<u>125</u>

470 3 <u>M</u>
(4)

<u>I</u>

类型 Type					
	闭磁路贴片电感				
SDRI	Shielded SMD Power Inductors				

2

外形尺寸(L×W×H) (mm)			
External Dimensions (L×W×H)			
(mm)			
125	12.3×12.3×6.0		

(3)

Inductance 47 uH

4

公差 Inductance Tolerance

J:±5%,K: ±10%, L: ±15% M: ±20%,P: ±25%, N: ±30% (5

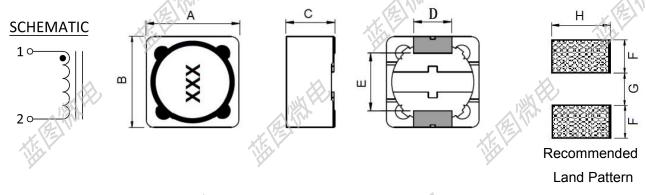
	ALVAIL		
<	2	包装 Packing	7
Ö	В	散装Bulk Package	
	Т	编带Tape & Reel	





# ◆外观尺寸:

# Shape and Dimensions (dimensions are in mm):



Dort No.	nk.	(I)		ITEM				
Part No	A	В	С	DA	F	F	G	HA
SDRI125	12.5 Max	12.5 Max	6.0 Max	5.0	7.6	2.9	7.0	5.4

# ◆规格特性:

# Specifications:

• SDRI125 Series Electrical Characteristics (Electrical specifications at 25℃)

				•				
A PARTY	lr	nductano	e	<b>*</b>	uality actor	DCR	Saturation Current	Temperature Rise Current
Part No	L(µH)	Tole	Test	Min	Test	(Ω)	(A)	(A)
	'@0A	. A	Freq		Freq	Max	Max	Max
SDRI125-1R0N	1.0	±30%	100KHz	20	1MHz	0.010	15.80	8.00
SDRI125-2R2N	2.2	±30%	100KHz	20	1MHz	0.014	13.50	7.80
SDRI125-2R4N	2.4	±30%	100KHz	20	1MHz	0.014	12.00	7.50
SDRI125-3R3N	3.3	±30%	100KHz	20	1MHz	0.017	10.50	6.80
SDRI125-4R7N	4.7	±30%	100KHz	30	1MHz	0.020	9.50	5.60
SDRI125-5R8N	5.8	±30%	100KHz	30	1MHz	0.021	8.60	5.20
SDRI125-8R2N	8.2	±30%	100KHz	30	1MHz	0.023	7.00	4.40
SDRI125-100N	10	±30%	100KHz	35	1MHz	0.025	6.50	4.00
SDRI125-120M	12	±20%	100KHz	35	1MHz	0.027	6.00	3.50
SDRI125-150M	15	±20%	100KHz	35	1MHz	0.030	5.40	3.30
SDRI125-180M	18	±20%	100KHz	35	1MHz	0.034	4.90	3.00
SDRI125-220M	22	±20%	100KHz	35	1MHz	0.036	4.70	2.80
SDRI125-270M	27	±20%	100KHz	35	1MHz	0.051	4.00	2.30
SDRI125-330M	33	±20%	100KHz	35	1MHz	0.057	3.58	2.10
SDRI125-390M	39	±20%	100KHz	35	1MHz	0.068	3.30	2.00
SDRI125-470M	47	±20%	100KHz	35	1MHz	0.075	3.20	1.80
SDRI125-560M	56	±20%	100KHz	35	1MHz	0.110	2.80	1.70
SDRI125-680M	68	±20%	100KHz	35	1MHz	0.120	2.50	1.50
SDRI125-820M	82	±20%	100KHz	35	1MHz	0.140	2.30	1.40
SDRI125-101M	100	±20%	100KHz	40	0.796MHz	0.160	1.90	1.30
SDRI125-121M	120	±20%	100KHz	40	0.796MHz	0.170	1.80	1.10
SDRI125-151M	150	±20%	100KHz	40	0.796MHz	0.230	1.70	1.00

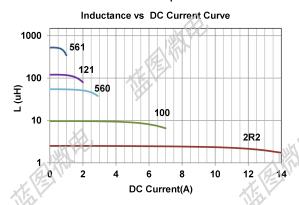
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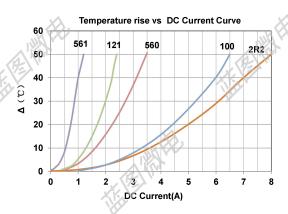




Dowl Ma	lı A	nductano	e		uality actor	DCR	Saturation Current	Temperature Rise Current
Part No	L(µH) '@0A	Tole	Test Freq	Min	Test Freq	(Ω) Max	(A) Max	(A) Max
SDRI125-181M	180	±20%	100KHz	40	0.796MHz	0.290	1.60	0.90
SDRI125-221M	220	±20%	100KHz	40	0.796MHz	0.400	1.45	0.80
SDRI125-271M	270	±20%	100KHz	40	0.796MHz	0.460 👍	1.20	0.75
SDRI125-331M	330	±20%	100KHz	40	0.796MHz	0.510	1.15	0.68
SDRI125-391M	390	±20%	100KHz	40	0.796MHz	0.690	1.10	0.65
SDRI125-471M	470	±20%	100KHz	40	0.796MHz	0.770	0.94	0.58
SDRI125-561M	560	±20%	100KHz	40	0.796MHz	0.860	0.90	0.54
SDRI125-681M	680	±20%	100KHz	40	0.796MHz	1.200	0.70	0.48
SDRI125-821M	820	±20%	100KHz	40	0.796MHz	1.340	0.55	0.40
SDRI125-102M	1000	±20%	100KHz	40	0.796MHz	1.530	0.44	0.35

- Saturation Current: DC current at which inductance drops 30% from its value without current.
- Temperature Rise Current: the actual value of DC current when the temperature rise is △T 40 °C (Ta=25 °C).
- Rated DC Current: The less value which is Isat or Irms.
- Special remind:Circuit design, component, PCB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.
- Saturation current VS temperature rise current curve

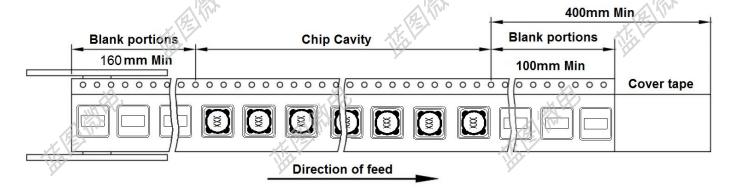




◆产品包装:

Packaging:

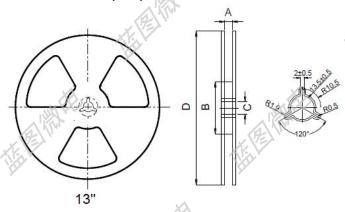
• Tape and Reel Specifications: (Dimensions are in mm)



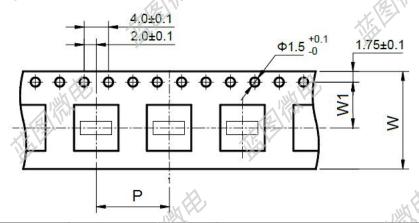




### • Reel Dimensions (mm)

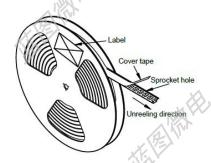


# ●Tape Dimension (mm)

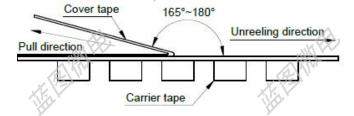


Part No.	Tape Dimension			Reel Dimensions			REEL	Inside	Outside	
Part NO.	W	P	Н	Α	В	С	D	(PCS)	Box(PCS)	Carton(PCS)
SDRI125	24	16	11.5	24.4	100	13	330	500	1000	4000

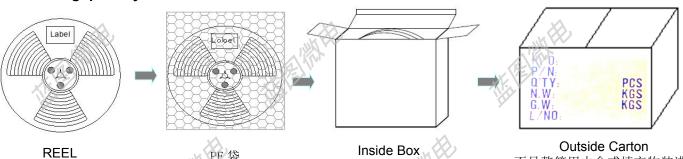
# • Cover tape peel off condition



- a) Cover tape peel force shall be 10 to 120g
- b) Noodle strip peeling angle165° to 180°



### • Packing quantity







# ◆可靠性测试:

# Reliability Testing:

		Trondomty resting.
Items	Requirements	Test Methods and Remarks
ments: GB/T 2423.60-2008	1. Pulling test:  Define: A: sectional area of terminal  A ≤ 8mm2 force ≥ 5N time:30sec  8mm2 <a 10n="" 10sec="" 2.solder="" 20mm2="" 20mm2<a="" 20n="" 3.meet="" above="" any="" force="" loose="" paste="" requirements="" td="" terminal<="" the="" thickness:0.12mm="" time:="" without="" ≤="" ≥=""><td>Solder the inductor to the testing jig using leadfree solder. Then apply a force in the Keep time: 10±1s Speed: 1.0mm/s.</td></a>	Solder the inductor to the testing jig using leadfree solder. Then apply a force in the Keep time: 10±1s Speed: 1.0mm/s.
erminal Strength Reference docu ments: GB/T 2423.60-2008 端子強度(DIP)		Pull Force:the force shall be applied gradually to the terminal and thenmaintained for 10 seconds.  F  Pulling test
Resistance to Flexure JIS C 5321:1997 抗弯曲性试验	推進	1.Solder the inductor to the test jig (glass epoxy board  2.shown in Using a leadfree solder. Then apply a force in the direction shown  3.Flexure: 2mm.  4.Pressurizing Speed: 0.5mm/sec.  5.Keep time: 30 sec.
Dropping Reference documents:  GB/T 2423.7-2018	inappearance.	1.Drop the packaged products from 1m high in 1 angle, 3 ridges and 6surfaces, twice in each direction.
落下試驗	ε.ινο σποιτ απά πο ορ <del>ο</del> π.	un conorr.
Solderability Reference documents: GB/T 2423.28-2005	3.Terminals must have 95% minimum solder	<ul> <li>1.Solder temperture:240±2℃</li> <li>2.Duration: 3 sec.</li> <li>3. Solder: Sn/3.0Ag/0.5Cu.</li> <li>4.Flux: 25% Resin and 75% ethanol in weight</li> </ul>





Items	Requirements	Test Methods and Remarks
	1.No visible mechanical damage.	1.Solder the inductor to the testing jig (glass epoxy
	2. Inductance change: Within ±10%.	boardshown in ) using leadfree solder.
	3.Q factor change: Within ±20%.	2.The inductor shall be subjected to a simple
	Cu pad Solder mask	harmonic motion having total amplitude of 1.5mm.
		the frequency being varieduniformly between the
XY. VEX		approximate limits of 10 and 55 Hz.
Vibration		3.The frequency range from 10 to 55 Hz and
Reference documents:		return to 10 Hz shallbe traversed in approximately
GB/T 2423.10-2019	Glass Epoxy Board	1 minute. This motion shall be applied for a period
振動試验	E True	of 2 hours in each 3mutually perpendicular
	TELL TELL	directions(total of 6 hours).
	Y	Freq
<i>X</i> A.	<i>X</i> 3.	55Hz
White the same of		
E No	是为	10Hz V V V V Time
	TEL Y	Time Time
	1.No visible mechanical damage.	1.Start at ( 85~125℃) for T time, rush to
	W(X)	(-55~40℃) for T time as one cycle, go through100
	Within ≤ 30%)	cycles.
Thermal Shock	3 Q factor change: Within ±20%.	2.Transforming interval: Max. 20 sec.
Reference documents:	litte little	3.Tested cycle: 100 cycles.
GB/T 2423.22-2012		4. The chip shall be stabilized at normal condition
Method Na	A Nu.	for 1~2 hours
冷热冲击试验	A KIT	125°C/85°C 30 min. 30 min.
N. V.	W. C.	Ambient
, in	<i>y</i>	Temperature 30 min.
	×2	20sec. (max.)
	W. Company	Who will be
	1.No visible mechanical damage.	1.Temperature:M(-55~-40±2℃)
	2. Inductance change: Within ±10%.(Mn-Zn:	2.Duration: 96±2 hours
Low temperature Storage		3.The chip shall be stabilized at normal condition for
Reference documents:	3.Q factor change: Within ±20%.	1~2 hoursbefore measuring.
GB/T 2423.1-2008		Room
Method Ab	火星	Temp 0 96H Test
低温储存试验	THE .	97H 98H Time
·		M°C Low temperature
	XA.	Temp





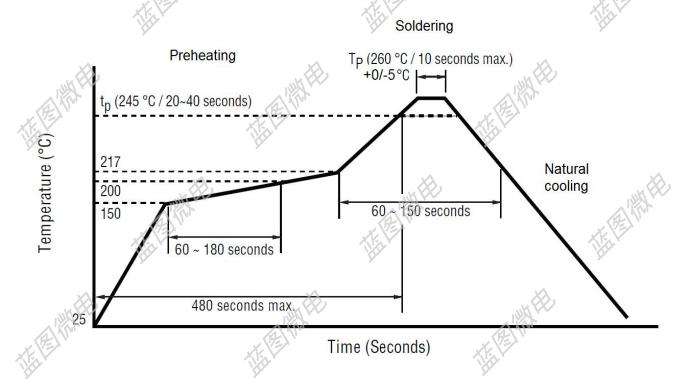
Items	Requirements	Test Methods and Remarks
	1.No visible mechanical damage.	1.Temperature:N(125~85±2℃).
High temperature	2. Inductance change: Within ±10%.(Mn-Zn:	2.Duration: 96±2 hours
Storage	Within ≦30%)	3.The chip shall be stabilized at normal condition
Reference documents:	3.Q factor change: Within ±20%.	for 1~2 hoursbefore measuring.
GB/T 2423.2-2008	E KINT	High temperature
Method Bb	XEXE.	NE LE
高温储存试验	, it	Room Temp
		0 96H 97H 98H Time
	No visible mechanical damage.	1.Temperature: 60±2°C
	2. Inductance change: Within ±10%.(Mn-Zn:	
Damp Heat	Within $\leq 30\%$ )	3.Duration: 96±2 hours.
(Steady States)	3.Q factor change: Within ±20%.	4.The chip shall be stabilized at normal condition
Reference documents:	e. Gradier Grange. William 220 %.	for 1~2 hoursbefore measuring.
GB/T 2423.3-2016	WHEE	Temp
恒定湿热试验	E TW	93%RH High femperature
	TELL TELL TELL TELL TELL TELL TELL TELL	Room Conditions
<i>y</i>	Y	Test 0 96H 97H 98H Time
Heat endurance of	1.No significant defects in appearance.	XX
Reflow soldering	2. △ L/L ≤ 10% (Mn-Zn: △ L/L ≤ 30%)	1 Refer to the above reflow curve and go through the reflow for twice.
	3. ∆ Q/Q ≤ 30% (SMD series only)	2.The peak temperature : 260+0/-5°C
GJB 360B-2009	4. △ DCR/DCR ≦ 10%	
回流焊耐热性试验		·
- 20,	No case deformation or change in	To dip parts into IPA solvent for 5±0.5Min,then
Resistance to solvent	appearance or obliteration of marking	drying them at room temp for 5Min,at last ,to
test Reference documents:	r Ell	brushing making 10 times.
IEC 68-2-45:1993	The state of the s	Hit.
耐溶剂性试验		
		14 D
Overload test	1.During the test no smoke, no peculiar,	
	smell, no fire	Apply twice as rated current for 5 minutes.
	2.The characteristic is normal after test	Hit
过负荷试验	1.During the test no breakdown	
voltage resistance test Reference documents:	2.The characteristic is normal after test	ul
MIL-STD-202G Method		1. For parts with two coils
301	XEVE Y	2. DC1000V, Current: 1mA, Time: 1Min.
绝缘耐压测试	)tr	Refer to catalogue of specific products





### ◆推荐回流焊温度曲线

### Recommended reflow soldering curve:



The recommended reflow conditions as above graph, is set according to our soldering equipment. DUE to various manufactures may have different reflow soldering equipment, products, process conditions, set methods. And so on, when setting the reflow conditions, Please adjust and confirm according to users' environment/equipment.



### 使用注意事项

# REMINDERS FOR USING THESE PRODUCTS



● 保存时间为12 个月以内,保存条件(温度5~40°C以下、湿度35 ~ 66%RH 以下),需充分注意 若超过保存时间,端子电极的可焊性将可能老化。

The storage period is within 12 months. Be sure to follow the storage conditions (temperature: 5~40°C, humidity: 35 to 65% RH or less). If the storage period elapses, the soldering of the terminal electrodes may deteriorate.

- 请勿在气体腐蚀环境(盐、酸、碱等)下使用和保存。
  - Do not use or store in locations where there are conditions such as gas corrosion (salt, acid, alkali, etc.).
- 手上的油脂会导致可焊性降低,应避免用手直接接触端子。
  - Don't touch electrodes directly with bare hands as oil secretions may inhibit soldering Always ensure optimum conditions for soldering.
- 请小心轻拿轻放,避免由于产品的跌落或取出不当而导致的损坏。
  - Please always handle products carefully to prevent any damage caused bydropping down or inappropriate removing.
- 端子过度弯曲会导致断线,请不要过度弯曲端子。
  - Don't bend the terminals with excessive stress in case of any wire fracture  $_{\mbox{\tiny o}}$
- 不要清洗产品, 如需要清洗时请联系我司。
  - Don't rinse coils by yourself and please contact SXN if necessary.
- 请勿将本产品靠近磁铁或带有磁力的物体
  - Don't expose the products to magnets or magnetic fields
- 在实施焊接前,请务必进行预热。预热温度与焊接温度及芯片温度的温度差要在150°C 以内。 Before soldering, be sure to preheat components. The preheating temperature should be set so that the temperature difference between the solder temperature and chip temperature does not exceed 150°C.
- 安装后的焊接修正应在规格书规定的条件范围内。若加热过度可能导致短路、性能降低、寿命减少。 Soldering corrections after mounting should be within the range of the conditions determined in the specifications. If overheated, a short circuit, performance deterioration, or lifespan shortening may occur.
- 装置会因通电而自我发热(温度上升),因此在热设计方面需留有充分余地。
   Self heating (temperature increase) occurs when the power is turned ON, so the tolerance should be sufficient for the set thermal design.
- 非磁屏蔽型在基板设计时需注意配置线圈,受到电磁干扰可能会导致误动作。

  Carefully lay out the coil for the circuit board design of the non-magnetic shield type. A malfunction may occur due to magnetic interference.